



20V N-Channel Enhancement Mode MOSFET - ESD Protected

Voltage 20 V Current 6.5A

Features

- RDS(ON), VGS@4.5V, ID@6.5A<22mΩ
- RDS(ON), VGS@2.5V, ID@5.5A<26mΩ
- RDS(ON) , VGS@1.8V, ID@5.0A<34mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

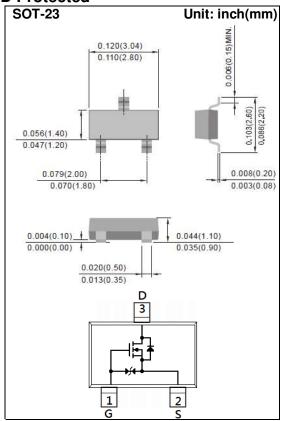
Mechanical Data

• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0003 ounces, 0.0084 grams

Marking: A6E



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	20	V
Gate-Source Voltage		V_{GS}	<u>+</u> 8	V
Continuous Drain Current		I _D	6.5	Α
Pulsed Drain Current (Note 4)		I _{DM}	32	Α
Power Dissipation	T _a =25°C	P _D	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C
Typical Thermal resistance - Junction to Ambient (Note 3)		$R_{ heta JA}$	100	°C/W





Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	0.4	0.58	1.0	V
Drain-Source On-State Resistance	R _{DS(on)}	V_{GS} =4.5V, I_{D} =6.5A	-	18.4	22	mΩ
		V _{GS} =2.5V, I _D =5.5A	-	21.5	26	
		V _{GS} =1.8V, I _D =5.0A	-	26.4	34	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =20V, V_{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	$V_{GS}=\pm 8V, V_{DS}=0V$	-	-	<u>+</u> 10	uA
Dynamic						
Total Gate Charge	Q_g	V _{DS} =10V, I _D =6.5A, V _{GS} =4.5V ^(Note 1,2)	-	8.6	-	nC
Gate-Source Charge	Q_gs		-	1.06	-	
Gate-Drain Charge	Q_{gd}	V _{GS} =4.5V	-	1.04	-	
Input Capacitance	Ciss		-	836	-	pF
Output Capacitance	Coss	$V_{DS}=10V, V_{GS}=0V,$	-	96	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	80	-	
Switching						
Turn-On Delay Time	td _(on)	\/ 40\/ L 4A	-	24	-	
Turn-On Rise Time	tr	$V_{DD}=10V, I_{D}=1A,$	-	46	-	ns
Turn-Off Delay Time	td _(off)	$V_{GS}=4.5V$, $R_{G}=3\Omega$ (Note 1,2)	-	0.22	-	us
Turn-Off Fall Time	tf	R _G =312	-	0.30	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					1.5	А
Diode Forward Current	I _S		-	-	1.5	
Diode Forward Voltage	V _{SD}	I _S =1.0A, V _{GS} =0V	-	0.74	1.0	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R_{ΘJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.





TYPICAL CHARACTERISTIC CURVES

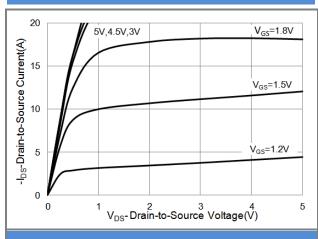


Fig.1 On-Region Characteristics

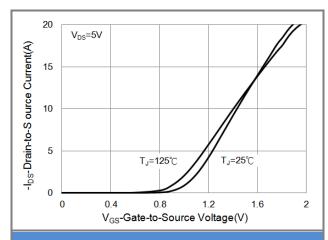


Fig.2 Transfer Characteristics

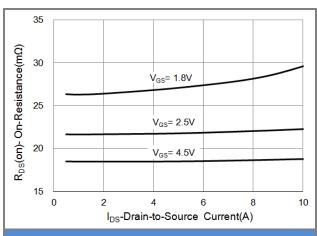


Fig.3 On-Resistance vs. Drain Current

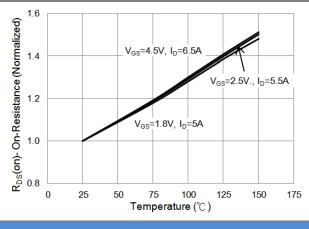
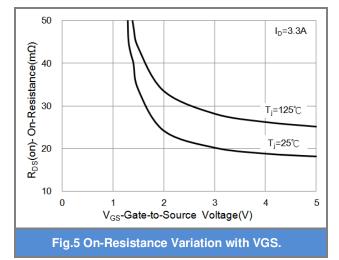
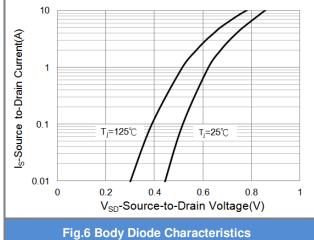


Fig.4 On-Resistance vs. Junction temperature

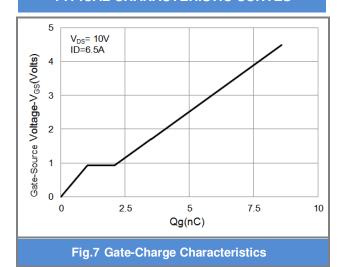








TYPICAL CHARACTERISTIC CURVES



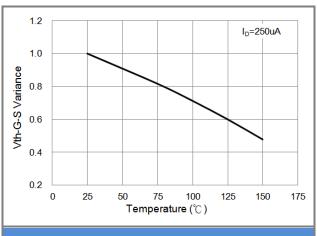


Fig.8 Threshold Voltage Variation with Temperature.

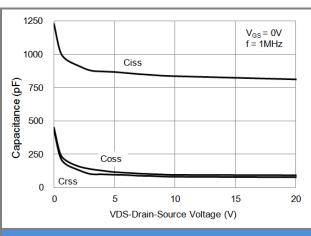


Fig.9 Capacitance vs. Drain-Source Voltage.

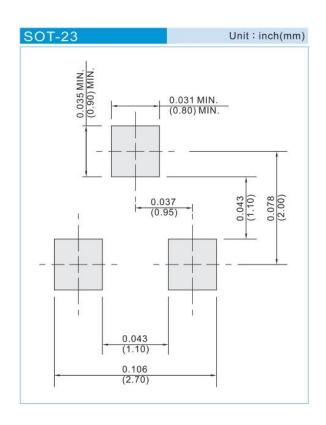




PART NO PACKING CODE VERSION

PART NO PACKING CODE	Package Type	Packing type	Marking	Version
PJA3416AE_R1_00001	SOT-23	3K pcs / 7" reel	A6E	Halogen free
PJA3416AE_R2_00001	SOT-23	12K pcs / 13" reel	A6E	Halogen free

MOUNTING PAD LAYOUT







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